TOSHIBA TA8062AS

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8062AS

DUAL HIGHSIDE DRIVER

The TA8062AS is a 0.3A highside driver containing two circuits in one package.

The input level is TTL compatible so that the output can be controlled directly from CPU system and the like. Protective functions are built in to protect IC and load from destruction caused of over stress.

FEATURES

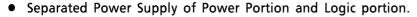
2 circuit in one package.

Output current capacity: 0.3A

Low Standby Current : 100 μ A (Max.)

Protective function : Over-voltage Protection

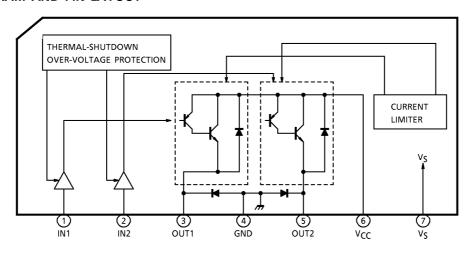
> **Current Limiter** Thermal-Shutdown



Bulit-in Counter Electromotive Force Absorption Diodes.

• SIP7pin Plastic Package.

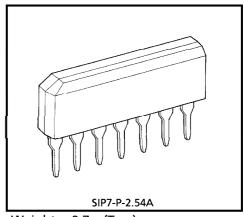
BLOCK DIAGRAM AND PIN LAYOUT



TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

The products described in this document are subject to foreign exchange and foreign trade control laws.
The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.



Weight: 0.7g (Typ.)

PIN No.	SYMBOL	DESCRIPTION
1	IN1	These terminals control output condition.
2	IN2	The input level is TTL Compatible. (IN1, IN2)→(Low, Low): Low Standby Current Mode 100μA (Max.)
3	OUT1	PNP-NPN complementary output pin with a current capacity of 0.3A. When the output pin is supplied with a current exceeding the detection current
5	OUT2	(typically 0.55A) because of load short-circuit, the output is limited to protect the IC.
4	GND	Grounded terminal.
6	V _{CC}	Power supply terminal for the output part of IC. Built-in over-voltage function protects IC and load when the supplied voltage is higher than 30V.
7	Vs	Power supply terminal for the control part of IC and this pin is separated from V _{CC} .

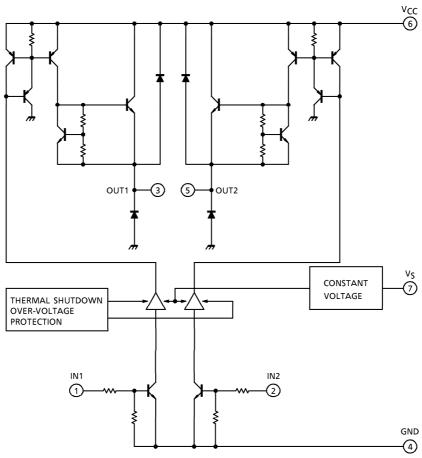
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	50 (1s)	V
Input Voltage	VIN	-0.3~V _{CC} +0.3	V
Output Current	lout	300	mA
Power Dissipation	PD	0.92	W
Operating Temperature	Topr	- 40~85	°C
Storage Temperature	T _{stg}	- 55∼150	°C
Lead Temperature·Time	T _{sol}	260 (10s)	°C

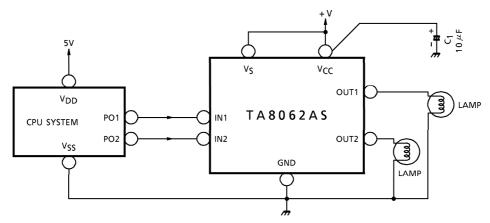
ELECTRICAL CHARACTERISTICS (V_S, V_{CC} = $8\sim16$ V, Ta = $-40\sim85$ °C)

CHARACTERISTIC	SYMBOL	PIN	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	I _{S1}	V _S		(IN1, IN2) = (L, L)			0.05	5 mA
Supply Current (I)	I _{S2}			(IN1, IN2) = (L, H) or (H, L)		6	15	
	I _{S3}			(IN1, IN2) = (H, H)	_	9	20	
	^I CC1	Vcc		(IN1, IN2) = (L, L)	_	_	0.05	
Supply Current (II)	I _{CC2}			(IN1, IN2) = (L, H) or (H, L)		7.5	15	mA
	ICC3		_	(IN1, IN2) = (H, H)	_	14	30	
Innut Valtage	VIL	IN1	_	_	_	_	0.8	V
Input Voltage	VIH	/ IN2	_	_	2.0	_	_	V
Input Current	ΙL	IN1	_	V _{IN} = 0.4V		10	20	
input Current	ΊΗ	/ IN2	_	V _{IN} = 5V		170	350	μ A
Output Saturation Voltage	V _{sat}	OUT1 /OUT2	_	I _O = 300mA		1.0	1.5	V
Output Leakage Current	ILEAK	OUT1 /OUT2	1	V _{out} = 0V	- 100	_	_	μΑ
Diode Forward Voltage	V _F	OUT1 /OUT2	1	I _F = 200mA		1.1	_	٧
Output Limit Current	I _{SC}	OUT1 /OUT2	_	_	0.3	0.55	_	Α
Chartelesson Tanamanatuma	T _{SD-H}	OUT1		OUT = ON→OFF		150	_	0.0
Shutdown Temperature	T _{SD-L}	/OUT2	_	OUT = OFF→ON	_	130	_	°C
Over-Voltage Detection	V _{SD}	Vcc	_	_	27	30	33	V
Transfer Dalay Time	t _{pLH}		_	_	_	1	10	μs
Transfer Delay Time	t _{pHL}		_			1	10	

EQUIVALENT CIRCUIT



APPLICATION CIRCUIT



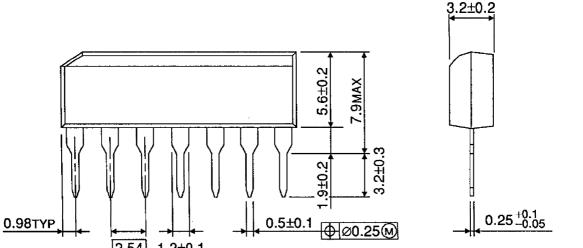
Cautions for wirings

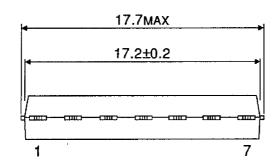
C₁ is for absorbing disturbance, noise, etc. Connect it as close to the IC as possible.

Unit: mm

OUTLINE DRAWING

SIP7-P-2.54A





2.54 1.2±0.1

Weight: 0.7g (Typ.)

0.98TYP